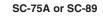
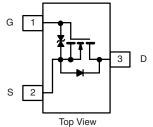


Vishay Siliconix

N-Channel 1.8 V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (mA)		
	0.70 at V _{GS} = 4.5 V	600		
20	0.85 at V _{GS} = 2.5 V	500		
	1.25 at V _{GS} = 1.8 V	350		





ORDERING INFORMATION				
Part Number	Package	Marking Code		
Si1012R-T1-GE3 (Lead (Pb)-free and Halogen-free)	SC-75A (SOT-416)	С		
Si1012X-T1-GE3 (Lead (Pb)-free and Halogen-free)	SC-89 (SOT-490)	А		

FEATURES

- TrenchFET[®] Power MOSFET: 1.8 V Rated
- Gate-Source ESD Protected: 2000 V
- High-Side Switching
- Low On-Resistance: 0.7 Ω
- Low Threshold: 0.8 V (typ.)
- Fast Switching Speed: 10 ns
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

BENEFITS

- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

ABSOLUTE MAXIMUM RATINGS (T	ſ _A = 25 °C, unless	otherwise not	ed)		
Parameter	Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	20		V
Gate-Source Voltage		V _{GS}	± 6		
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^{b}$	T _A = 25 °C		600	500	
	T _A = 85 °C		400	350	
Pulsed Drain Current ^a		I _{DM}	1000		mA
Continuous Source Current (Diode Conduction) ^b		۱ _S	275	250	1
	T _A = 25 °C		175	150	mW
Maximum Power Dissipation ^b for SC-75	T _A = 85 °C		90	80	
	T _A = 25 °C	P _D	275	250	
Maximum Power Dissipation ^b for SC-89	T _A = 85 °C	1	160	140	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000		V

Notes:

a. Pulse width limited by maximum junction temperature.

b. Surface mounted on FR4 board.

COMPLIANT

HALOGEN

Si1012R, Si1012X

Vishay Siliconix



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•		•		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$ 0			0.9	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$		± 0.5	± 1	μA	
		$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		0.3	100	nA	
Zero Gate Voltage Drain Current	IDSS	V_{DS} = 20 V, V_{GS} = 0 V, T_{J} = 85 $^{\circ}\text{C}$			5	μA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 4.5 V$	700			mA	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 600 \text{ mA}$		0.41	0.70		
				0.53	0.85	Ω	
				0.70	1.25		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 400 mA		1		S	
Diode Forward Voltage ^a	V _{SD}	I _S = 150 mA, V _{GS} = 0 V		0.8	1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			750			
Gate-Source Charge	Q _{gs}	V_{DS} = 10 V, V_{GS} = 4.5 V, I_{D} = 250 mA		75		рС	
Gate-Drain Charge	Q _{gd}			225		1	
Turn-On Delay Time	t _{d(on)}			5			
Rise Time	t _r	V_{DD} = 10 V, R_L = 47 Ω		5			
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ 200 mA, V_GEN = 4.5 V, R_g = 10 Ω	.5 V, R _g = 10 Ω			ns	
Fall Time	t _f			11		1	

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

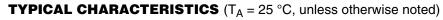
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

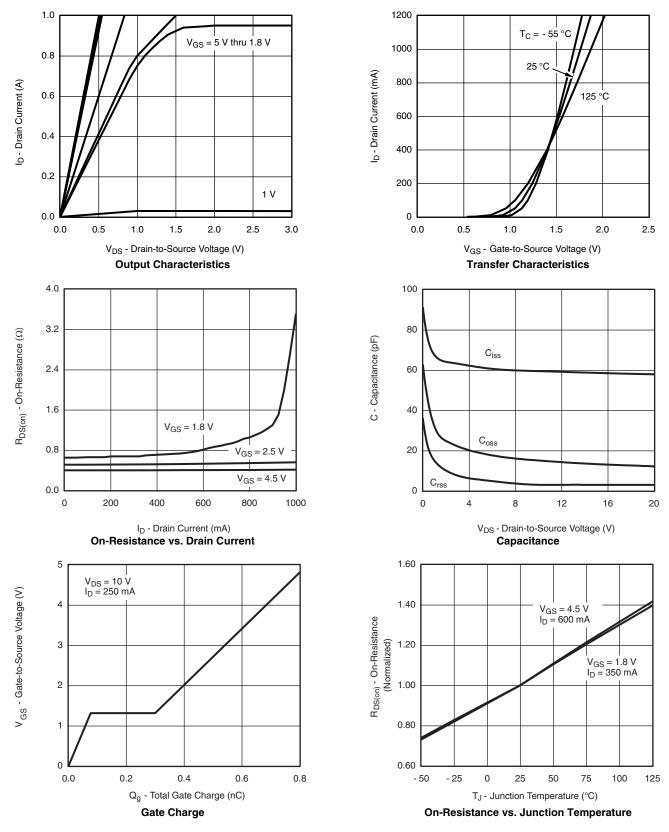
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Si1012R, Si1012X

Vishay Siliconix





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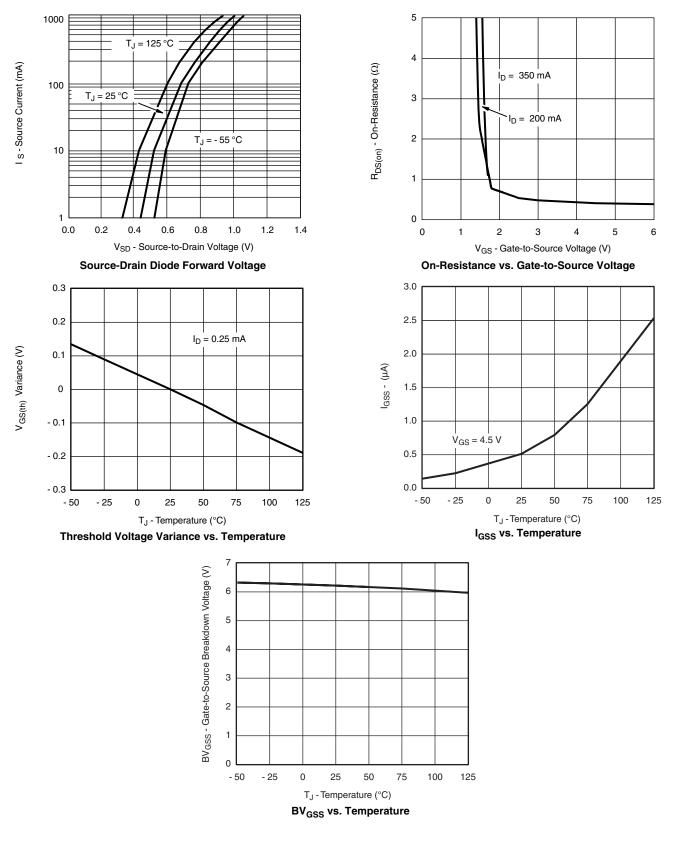
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Si1012R, Si1012X

Vishay Siliconix



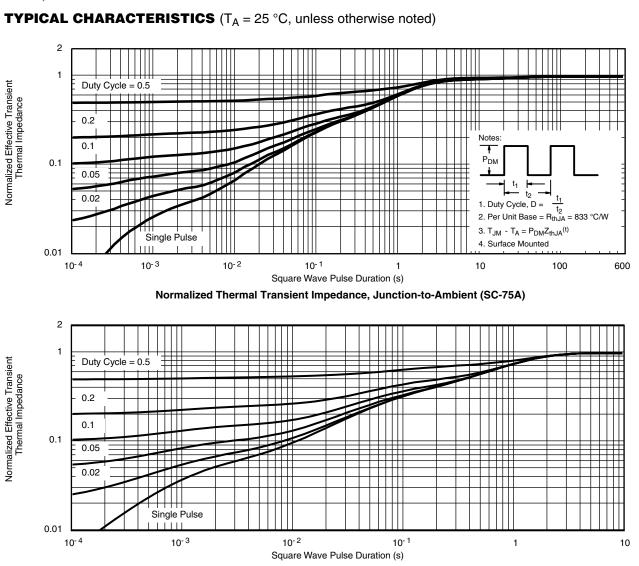
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



For technical questions, contact: pmostechsupport@vishay.com

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Si1012R, Si1012X

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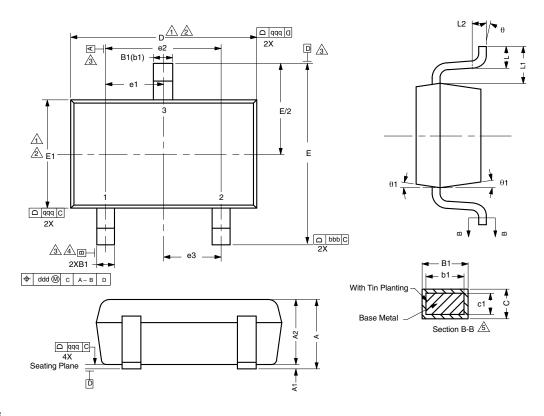
Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg271166.



Vishay Siliconix

SC-75A: 3 Leads



DWG: 5868

Notes

Dimensions in millimeters will govern.

- ⚠Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.
- 2 Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.
- A Datums A, B and D to be determined 0.10 mm from the lead tip.

A Terminal positions are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIMENSIONS	TOLERANCES
aaa	0.10
bbb	0.10
ссс	0.10
ddd	0.10

DIM.	P	/ILLIMETER	S	NOTE
Divi.	MIN.	NOM.	MAX.	NOTE
А	-	-	0.80	
A1	0.00	-	0.10	
A2	0.65	0.70	0.80	
B1	0.19	-	0.24	5
b1	0.17	-	0.21	
с	0.13	-	0.15	5
c1	0.10	-	0.12	5
D	1.48	1.575	1.68	1, 2
E	1.50	1.60	1.70	
E1	0.66	0.76	0.86	1, 2
e1				
e2				
e3				
L	0.15	0.205	0.30	
L1	0.40 ref.			
L2	0.15 BSC			
q	0°	-	8°	
q1	4°	-	10°	

C15-1445-Rev. F, 23-Nov-15

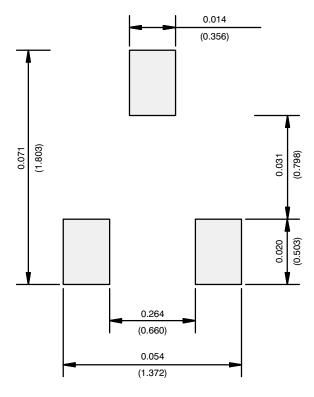
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Application Note 826

Vishay Siliconix

RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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